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PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

APPLICANT: Joseph J. Schottler

SERIAL NO.: 10/751,081

FILED: January 2, 2004

TITLE : HIGH SIDE NFET GATE DRIVING CIRCUIT

Group/A.U.: 2811 Conf. No.: 1318

Examiner : Tuan Thieu Lam

Docket No.: P06702US0

Mail Stop - Amendment Commissioner of Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sir:

AMENDMENT

In response to the Office Action dated June 7, 2005, please amend the above-identified application as follows:

Remarks/Arguments begin on page 2 of this paper.